



D12V0H1U2LP1610

1 CHANNEL HIGH SURGE TVS DIODE

Product Summary

\/ /Mim)		$C_{-}(T_{1}m)$
V _{BR} (Min) I _P	_P (Max)	Ст(Тур)
13V	50A	350pF

Description

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for use in portable applications such as cellular phones, digital cameras and MP3 players.

Applications

- Cellular Handsets
- Portable Electronics
- Computers and Peripheral

Features

- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±30kV, Contact ±30kV
- One Channels of ESD Protection
- Low Channel Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN1610-2 (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiAu Bump. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.003 grams (Approximate)



Device Schematic

Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D12V0H1U2LP1610-7	Standard	QD3	7	8	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Data Cada Kau

Notes:



QD3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key												
Year	20	15	20	16	20)17	20	18	20	019	20	20
Code	(0	[)		E		F		G	ł	4
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current	IPP	50	A	8/20µs (Note 7)
Peak Pulse Power Dissipation	P _{PP}	1,000	W	8/20µs (Note 7)
ESD Protection – Contact Discharge	V _{ESD_CONTACT}	±30	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	$V_{\text{ESD}_{AIR}}$	±30	kV	Standard IEC 61000-4-2

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient $T_A = +25^{\circ}C$	R _{θJA}	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

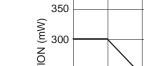
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	V _{RWM}	_	—	12	V	—
Channel Leakage Current (Note 6)	I _R	—	—	0.1	μA	V _R = 12.0V
Reverse Breakdown Voltage	V _{BR}	13	—	—	V	I _R = 1mA
	Vc	_	—	15.5	V	I _{PP} = 1A, t _P = 8/20µs
Clamping Voltage, Positive Transients (Note 7)		—	—	16.5	V	I _{PP} = 10A, t _P = 8/20µs
			—	20.0	V	I _{PP} = 50A, t _P = 8/20µs
Channel Input Capacitance (Note 8)	CT	_	350	_	pF	$V_R = 0V$, f = 1MHz, Any I/O to GND
Dynamic Resistance	R _{DYN}	_	0.05	—	Ω	TLP, 10A, t _P = 100ns

5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. website at http://www.diodes.com/package-outlines.html. 6. Short duration pulse test used to minimize self-heating effect. Notes:

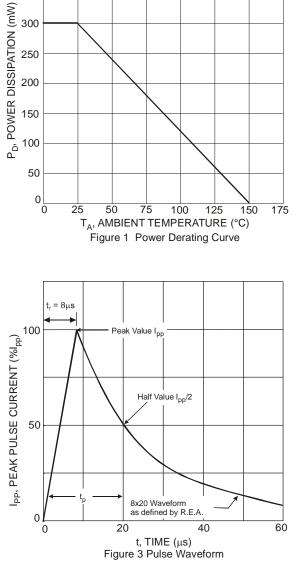
7. Clamping voltage value is based on an 8x20µs peak pulse current (IPP) waveform.

8. Measured from any I/O to GND.

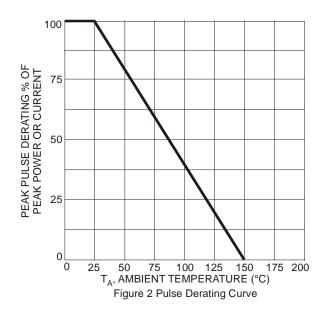
9. For information on the impact of Diodes' USB 2.0 compatible ESD protectors on signal integrity including eye diagram plots, please refer to AN77 at the following URL: http://www.diodes.com/destools/appnote_dnote.html.



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Note 5

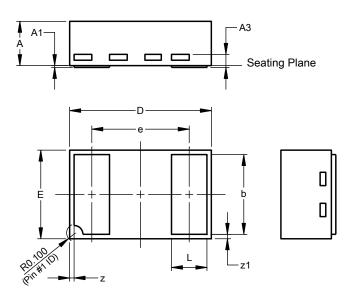




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1610-2 (Type B)

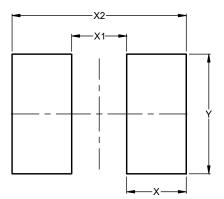


	U-DFN1610-2								
Dim	Min	(Type B) Min Max Typ							
Α	0.45	0.55	0.50						
A1	0.00	0.05	0.015						
A3	-	-	0.127						
b	0.85	0.95	0.90						
D	1.55	1.65	1.60						
E	0.95	1.05	1.00						
е	-	1.10							
L	0.35 0.45 0.40								
z	0.050 REF								
z1	0.050 REF								
All D	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1610-2 (Type B)



Dimensions	Value (in mm)
Х	0.650
X1	0.600
X2	1.900
Y	1.300



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